



## DESCRIPTION

The BAV99W is a smaller package, equivalent to the BAV99L

The BAV99W is available in SC-70 package

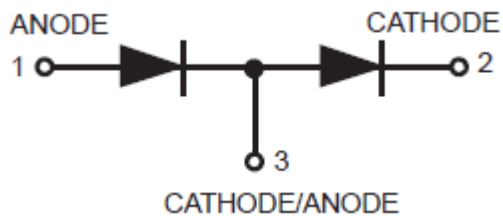
## FEATURES

- Available in SC-70 package

## ORDERING INFORMATION

Package Type	Part Number
SC-70	BAV99W
Note	3,000pcs/Reel
AiT provides all RoHS Compliant Products	

## PIN DESCRIPTION



## APPLICATION

- ESD Protection
- Polarity Reversal Protection
- Data Line Protection
- Inductive Load Protection
- Steering Logic



## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$

$V_R$ , Reverse Voltage	70Vdc
$I_F$ , Forward Current	215mAdc
$I_{FM(surge)}$ , Peak Forward Surge Current	500mAdc
$V_{RRM}$ , Repetitive Peak Reverse Voltage	70V
$I_{F(AV)}$ , Average Rectified Forward Current <sup>Note1</sup> (averaged over any 20 ms period)	715mA
$I_{FRM}$ , Repetitive Peak Forward Current	450mA
$I_{FSM}$ , Non-Repetitive Peak Forward Current	
$t = 1.0\mu\text{s}$	2.0A
$t = 1.0\text{ms}$	1.0A
$t = 1.0\text{S}$	0.5A

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL CHARACTERISTICS

Parameter	Symbol	Max	Unit
Total Device Dissipation FR-5 Board <sup>Note1</sup> $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	200 1.6	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate <sup>Note2</sup> $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{STG}$	-65 to +150	$^\circ\text{C}$

NOTE1: FR-5 = 1.0 x 0.75 x 0.062 in

NOTE2: Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina



## ELECTRICAL CHARACTERISTICS

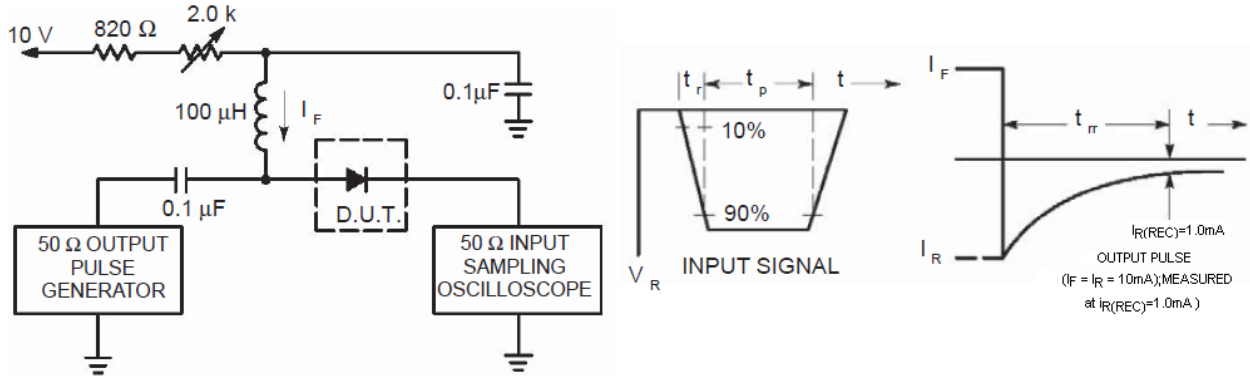
T<sub>A</sub> = 25 °C unless otherwise noted (Each Diode)

Parameter	Symbol	Conditions	Min.	Max.	Unit
<b>OFF CHARACTERISTICS</b>					
Reverse Breakdown Voltage	V <sub>(BR)</sub>	I <sub>(BR)</sub> = 100μA	70		Vdc
Reverse Voltage Leakage Current	I <sub>R</sub>	V <sub>R</sub> = 70Vdc		2.5	μAdc
		V <sub>R</sub> = 25Vdc, T <sub>J</sub> = 150°C		30	
		V <sub>R</sub> = 70Vdc, T <sub>J</sub> = 150°C		50	
Diode Capacitance	C <sub>D</sub>	V <sub>R</sub> = 0, f = 1.0 MHz		1.5	pF
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 1.0mAdc		715	mVdc
		I <sub>F</sub> = 10mAdc		855	
		I <sub>F</sub> = 50mAdc		1000	
		I <sub>F</sub> = 150mAdc		1250	
Reverse Recovery Time R <sub>L</sub> =100 Ω	t <sub>rr</sub>	I <sub>F</sub> =I <sub>R</sub> =10mAdc, I <sub>R(REC)</sub> =1.0mAdc(Figure 1)		6.0	ns
Forward Recovery Voltage	V <sub>FR</sub>	I <sub>F</sub> = 10mA, t <sub>r</sub> = 20ns		1.75	V



**TYPICAL CHARACTERISTICS**

Figure 1. Recovery Time Equivalent Test Circuit



Note1: A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 10mA.

Note2: Input pulse is adjusted so  $I_{R(peak)}$  is equal to 10mA.

Note3:  $t_p \gg t_{rr}$

Figure 2. Forward Voltage

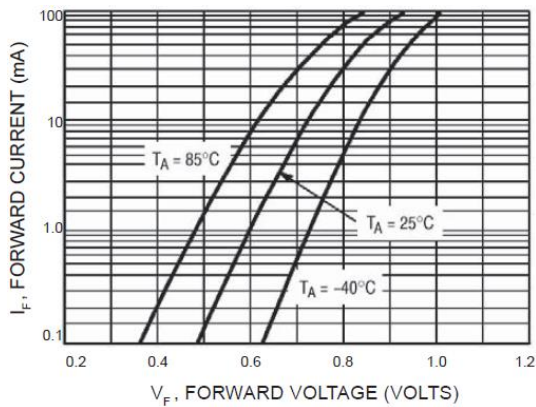


Figure 3. Leakage Current

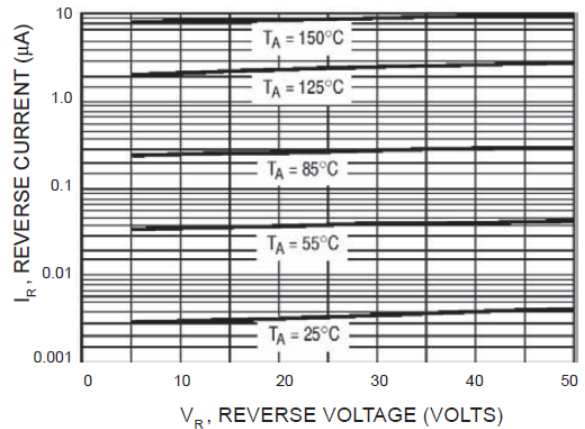
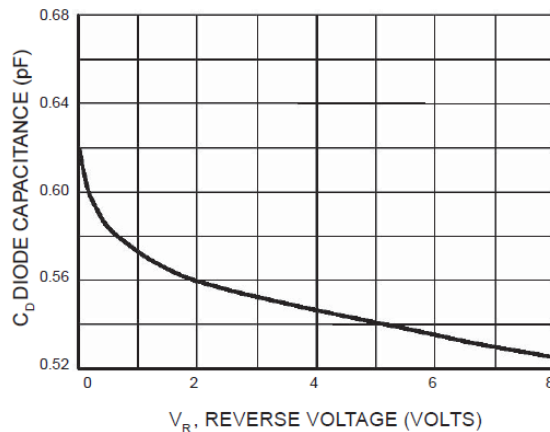


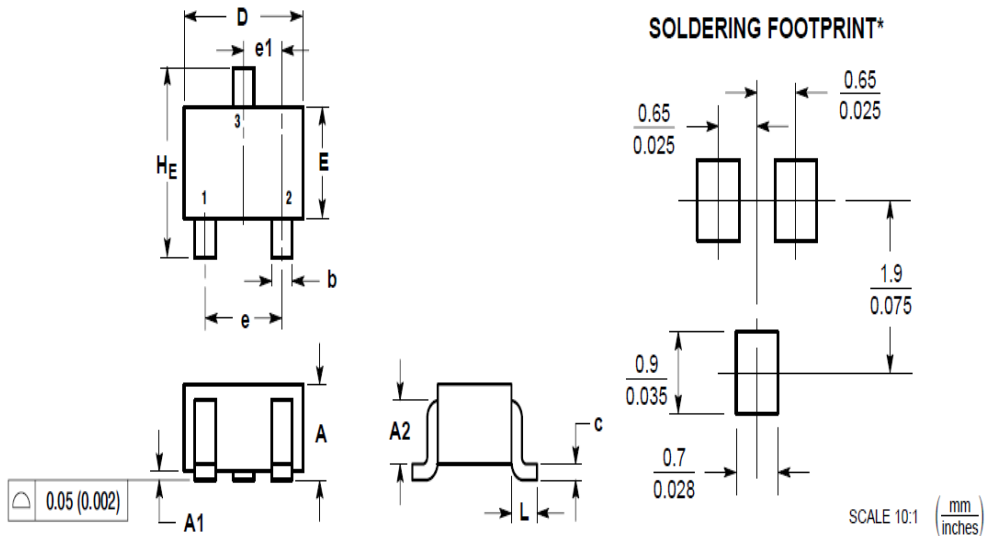
Figure 4. Capacitance





**PACKAGE INFORMATION**

Dimension in SC-70 Package (Unit: mm)



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.032	0.040
A1	0.00	0.10	0.000	0.004
A2	0.7 REF		0.028 REF	
b	0.30	0.40	0.012	0.016
c	0.10	0.25	0.004	0.010
D	1.80	2.20	0.071	0.087
E	1.15	1.35	0.045	0.053
e	1.20	1.40	0.047	0.055
e1	0.65 BSC		0.026 BSC	
L	0.425 REF		0.017 REF	
HE	2.00	2.40	0.079	0.095



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